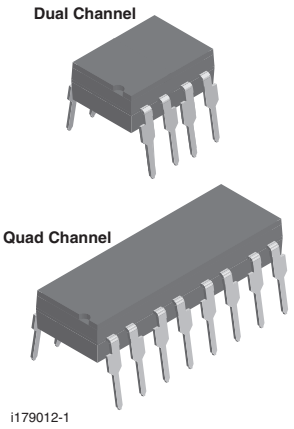
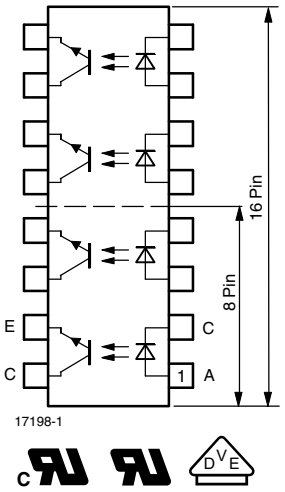
Optocoupler, Phototransistor Output, (Dual, Quad Channel)





FEATURES

- Extra low coupling capacity - typical 0.2 pF
- High common mode rejection
- Low temperature coefficient of CTR
- Rated impulse voltage (transient overvoltage) V_{IOTM} = 10 kV peak
- Creepage current resistance according to VDE 0303/IEC 60112 comparative tracking index: CTI ≥ 175
- Thickness through insulation ≥ 0.4 mm
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO

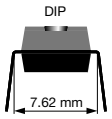
DESCRIPTION

The TCET2100/TCET4100 consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode, available in 8 pin (dual channel) and 16 pin (quad channel) package.

ORDERING INFORMATION

T	C	E	T	#	1	0	0

PART NUMBER



AGENCY CERTIFIED/PACKAGE	CTR (%)
UL, cUL, VDE	**50 to 600**
DIP-8, dual channel	TCET2100
DIP-16, quad channel	TCET4100

ABSOLUTE MAXIMUM RATINGS [1] (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT				
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10$ µs	I_{FSM}	1.5	A
Power dissipation		P_{diss}	100	mW
Junction temperature		T_j	125	°C
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5$, $t_p \leq 10$ ms	I_{CM}	100	mA
Power dissipation		P_{diss}	150	mW
Junction temperature		T_j	125	°C
COUPLER				
Isolation test voltage (RMS)	t = 1 s	V_{ISO}	5300	V_{RMS}
Isolation voltage		V_{IORM}	890	V_P
Total power dissipation		P_{tot}	250	mW
Operating ambient temperature range		T_{amb}	- 55 to + 100	°C
Storage temperature range		T_{stg}	- 55 to + 150	°C
Soldering temperature [2]	2 mm from case, t ≤ 10 s	T_{sld}	260	°C

Notes

[1] Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

[2] Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT						
Forward voltage	I_F = ± 50 mA	V_F		1.25	1.6	V
Junction capacitance	V_R = 0 V, f = 1 MHz	C_j		50		pF
OUTPUT						
Collector emitter voltage	I_C = 1 mA	V_{CEO}	70			V
Emitter collector voltage	I_E = 100 µA	V_{ECO}	7			V
Collector emitter cut-off current	V_{CE} = 20 V, I_F = 0, E = 0	I_{CEO}		10	100	nA
COUPLER						
Collector emitter saturation voltage	I_F = 10 mA, I_C = 1 mA	V_{CEsat}			0.3	V
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f_c		110		kHz
Coupling capacitance	f = 1 MHz	C_k		0.3		pF

Note

- Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
I_C/I_F	V_{CE} = 5 V, I_F = 5 mA	CTR	50		600	%

MAXIMUM SAFETY RATINGS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT						
Forward current		I_F			275	mA
OUTPUT						
Power dissipation		P_{diss}			400	mW
COUPLER						
Rated impulse voltage		V_{IOTM}			10	kV
Safety temperature		T_{si}			175	°C

Note

- According to DIN EN 60747-5-5 (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Partial discharge test voltage - routine test	100 %, t_{test} = 1 s	V_{pd}	1.669			kV
Partial discharge test voltage - lot test (sample test)	t_{Tr} = 60 s, t_{test} = 10 s, (see figure 2)	V_{IOTM}	10			kV
		V_{pd}	1.424			kV
Insulation resistance	V_{IO} = 500 V	R_{IO}	10^{12}			Ω
	V_{IO} = 500 V, T_{amb} = 100 °C	R_{IO}	10^{11}			Ω
	V_{IO} = 500 V, T_{amb} = 150 °C (construction test only)	R_{IO}	10^{9}			Ω

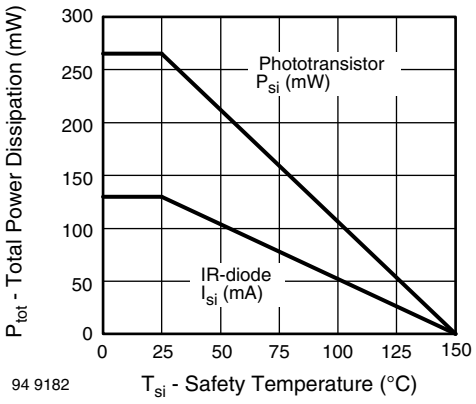


Fig. 1 - Derating Diagram

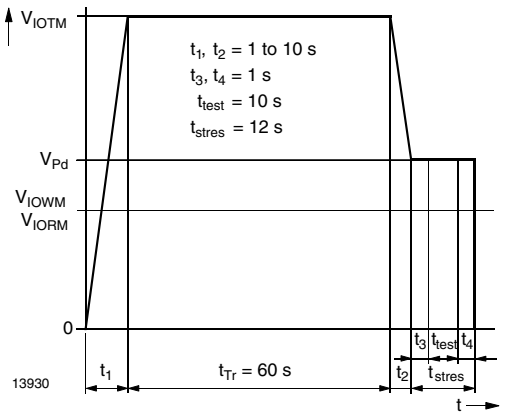


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC60747

SWITCHING CHARACTERISTICS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Delay time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω, (see figure 3)	t_d		3		µs
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω, (see figure 3)	t_r		3		µs
Turn-on time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω, (see figure 3)	t_{on}		6		µs
Storage time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω, (see figure 3)	t_s		0.3		µs
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω, (see figure 3)	t_f		4.7		µs
Turn-off time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω, (see figure 3)	t_{off}		5		µs
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 kΩ, (see figure 4)	t_{on}		9		µs
Turn-off time	V_S = 5 V, I_F = 10 mA, R_L = 1 kΩ, (see figure 4)	t_{off}		10		µs

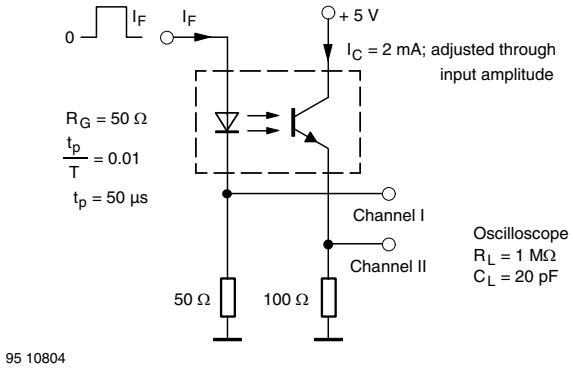


Fig. 3 - Test Circuit, Non-Saturated Operation

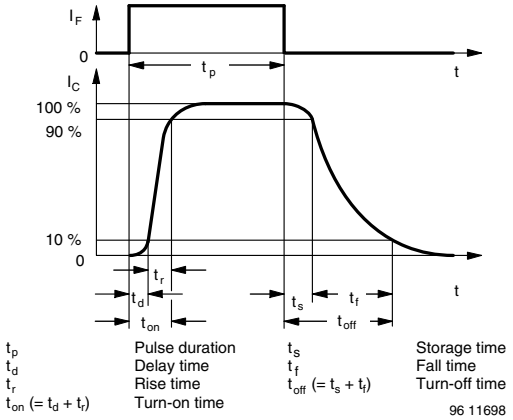


Fig. 5 - Switching Times

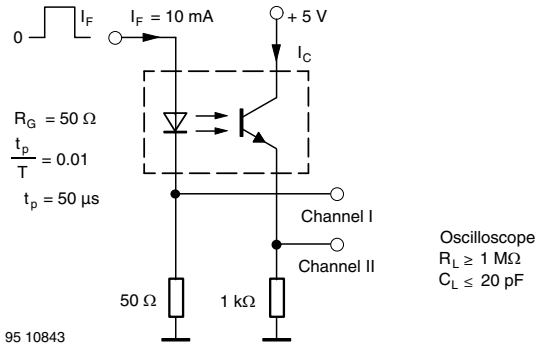


Fig. 4 - Test Circuit, Saturated Operation

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

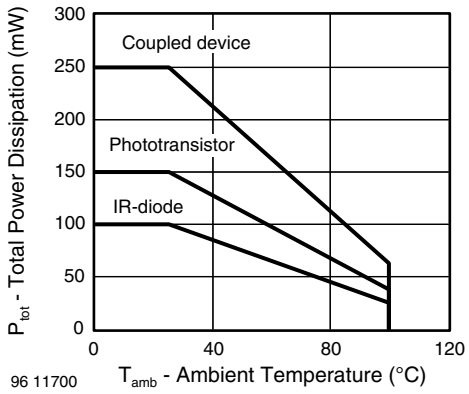


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

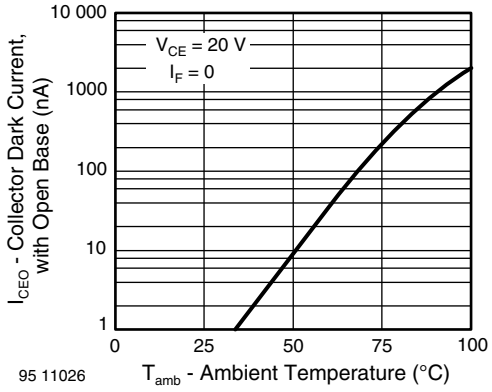


Fig. 9 - Collector Dark Current vs. Ambient Temperature

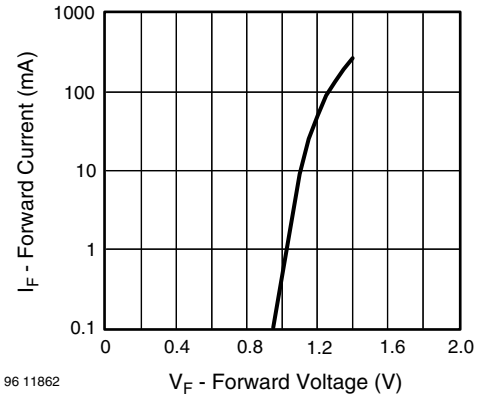


Fig. 7 - Forward Current vs. Forward Voltage

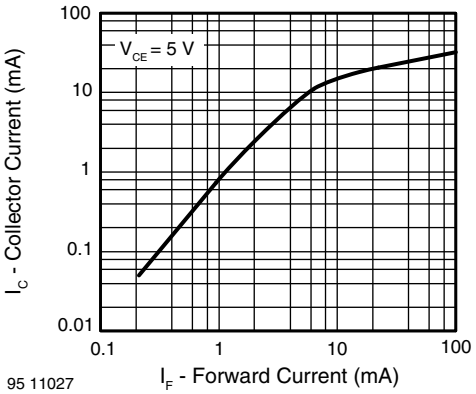


Fig. 10 - Collector Current vs. Forward Current

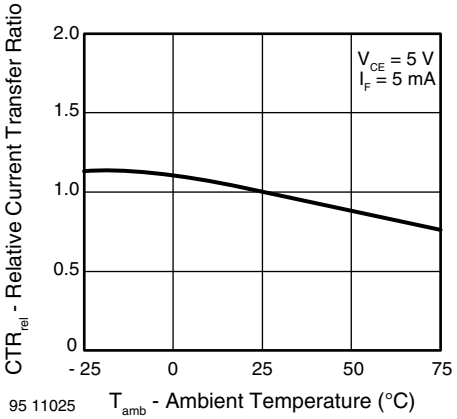


Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

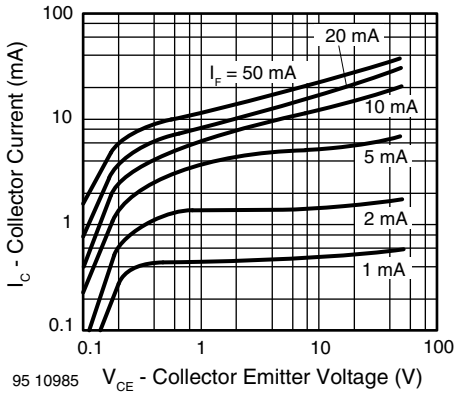


Fig. 11 - Collector Current vs. Collector Emitter Voltage

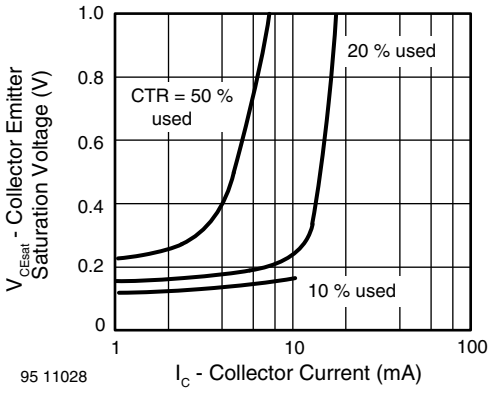


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

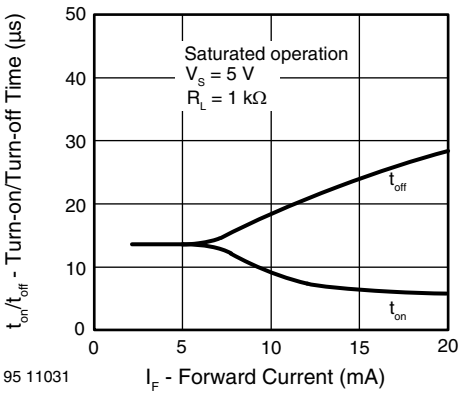


Fig. 15 - Turn-on/off Time vs. Forward Current

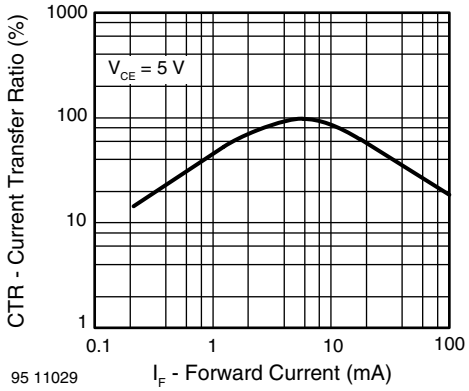


Fig. 13 - Current Transfer Ratio vs. Forward Current

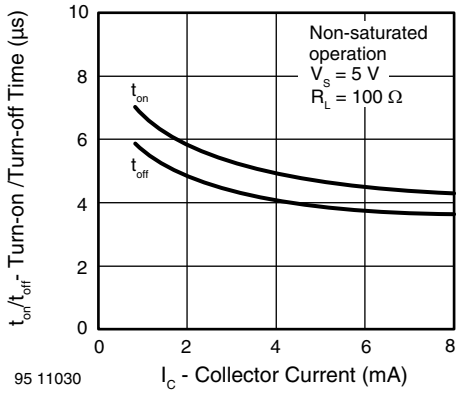
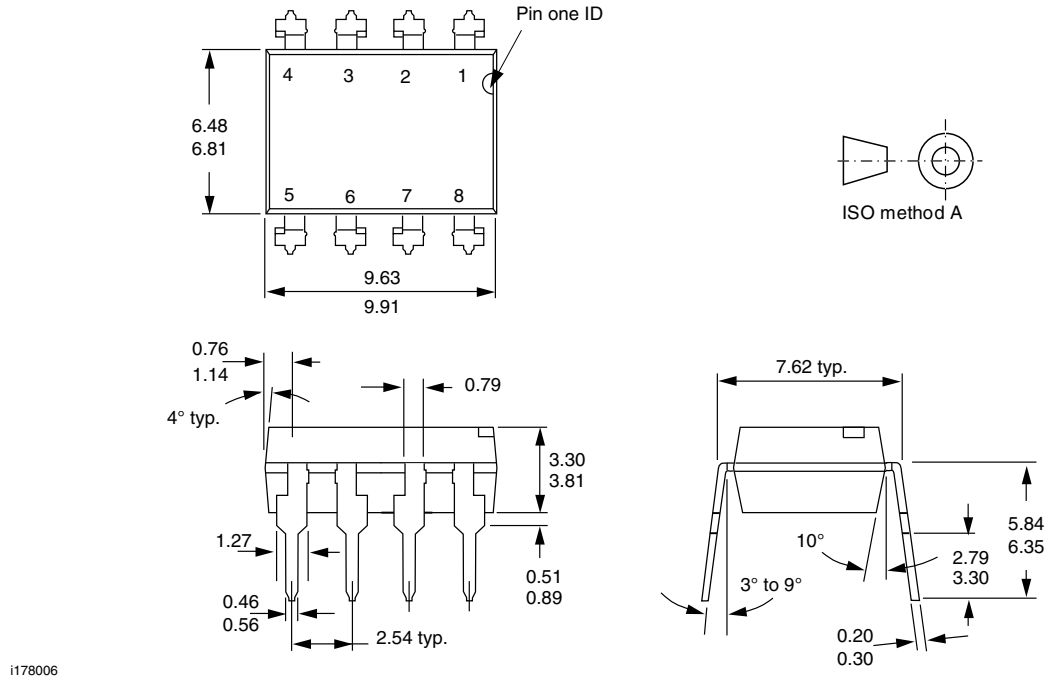
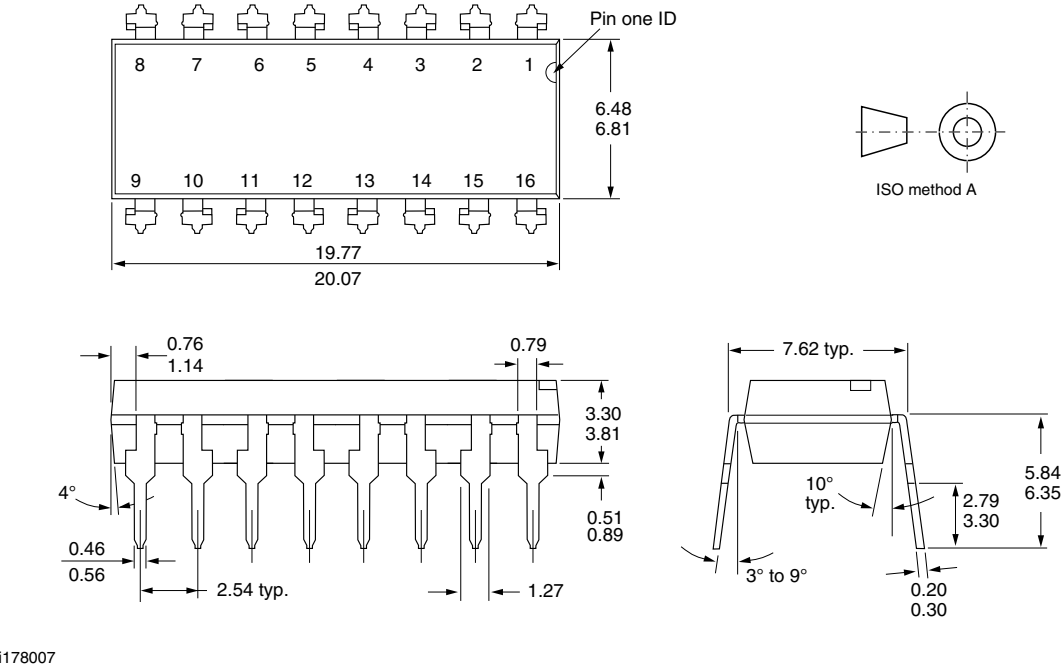


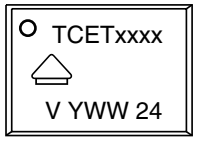
Fig. 14 - Turn-on/off Time vs. Collector Current

PACKAGE DIMENSIONS in millimeters





PACKAGE MARKING



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